



PATENT  
Customer No. 22,852  
Attorney Docket No. 03180.0326

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
)  
Tadashi IGUCHI et al. ) Group Art Unit: 2826  
)  
Application No.: 10/612,033 ) Examiner: Quinto, Kevin V.  
)  
Filed: July 3, 2003 )  
)  
For: SEMICONDUCTOR MEMORY )  
PREVENTING AN ELECTRIC )  
SHORT CIRCUIT BETWEEN A )  
WORD LINE AND A )  
SEMICONDUCTOR SUBSTRATE, )  
AND MANUFACTURING )  
METHOD FOR THE )  
SEMICONDUCTOR MEMORY )  
(AS AMENDED) )

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**AMENDMENT**

In response to the Office Action dated March 15, 2004, please amend the application as follows. The period for responding to the Office Action has been extended through September 15, 2004, by a Petition for Extension of Time and requisite fees filed concurrently herewith.

**Amendment to the Specification** is discussed on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims beginning on page 3 of this paper.

**Remarks** begin on page 11 of this paper.